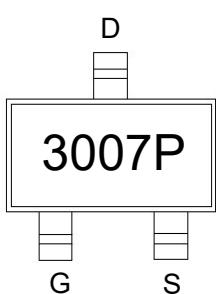


## Features

- Green Device Available
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

## Application

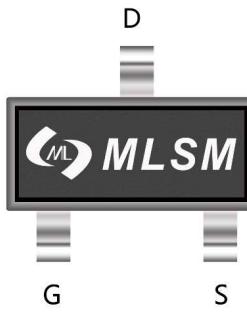
- Battery protection
- Load switch
- Power management



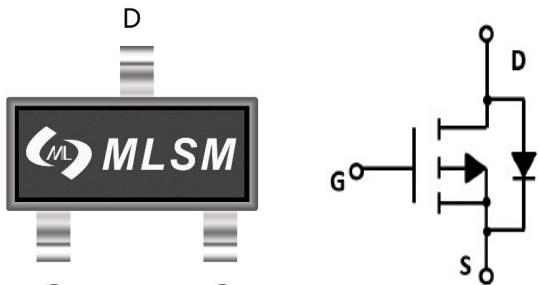
3007P: Device code

## Product Summary

V <sub>DS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX
-30V	30mΩ@-10V	-7A
	45mΩ@-4.5V	



SOT-23 top view



Schematic diagram



RoHS



Halogen-Free

Marking and pin assignment

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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## Common Ratings (TC=25°C Unless Otherwise Noted)

V <sub>DS</sub>	Drain-Source Breakdown Voltage	-30	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
T <sub>J</sub>	Maximum Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-50 to 155	°C
I <sub>S</sub>	Diode Continuous Forward Current	T <sub>C</sub> =25°C -7	A

## Mounted on Large Heat Sink

I <sub>DM</sub>	Pulse Drain Current Tested	T <sub>C</sub> =25°C	-36	A
I <sub>D</sub>	Continuous Drain Current	T <sub>C</sub> =25°C	-7	A
P <sub>D</sub>	Maximum Power Dissipation	T <sub>C</sub> =25°C	2.3	W
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient		45	°C/W

## Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLS3007P	SOT-23	3007P	3,000	45,000	180,000	7" reel

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250µA	-30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	--	--	-1	µA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250µA	-0.8	--	-2	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-10V, I <sub>D</sub> =-7A	--	20	30	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-5A	--	27	45	mΩ

**Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)**

C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1MHz	--	1200	--	pF
C <sub>OSS</sub>	Output Capacitance		--	155	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	140	--	pF
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =-15V, I <sub>D</sub> =-7A, V <sub>GS</sub> =-10V	--	52	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	10	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	8.5	--	nC

**Switching Characteristics**

t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =-15V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω	--	13	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	15	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	200	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	100	--	nS

**Source- Drain Diode Characteristics**

V <sub>SD</sub>	Forward on voltage	T <sub>j</sub> =25°C, I <sub>s</sub> =-7A	--	--	-1.2	V
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### Typical Operating Characteristics

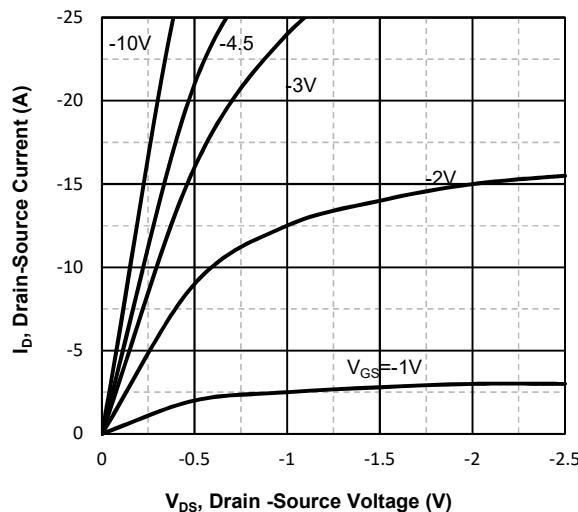


Fig1. Typical Output Characteristics

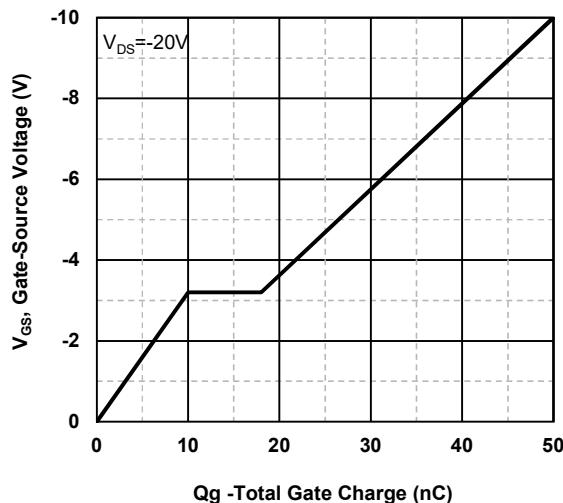


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

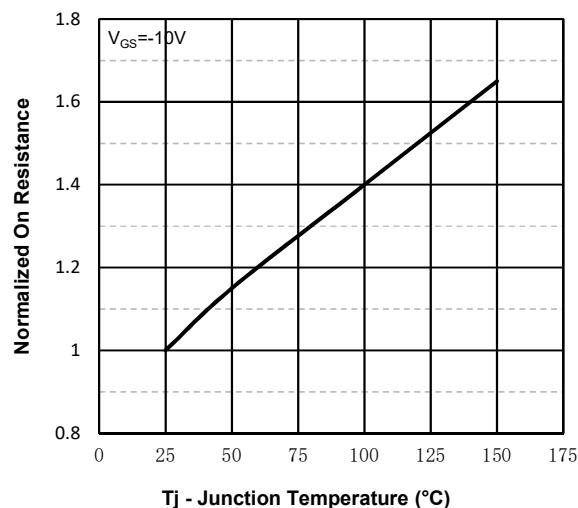


Fig3. Normalized On-Resistance Vs. Temperature

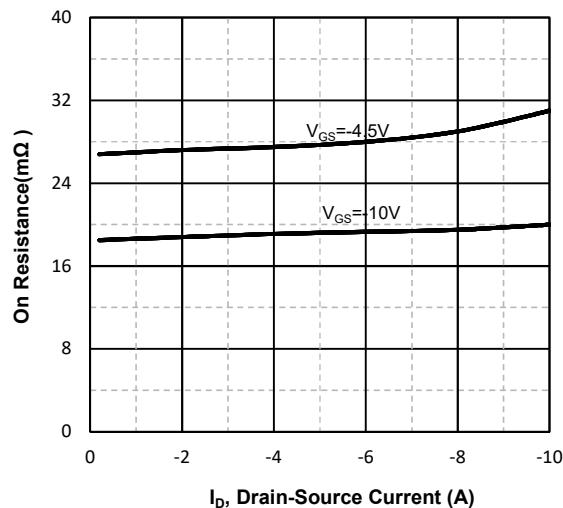


Fig4. On-Resistance Vs. Drain-Source Current

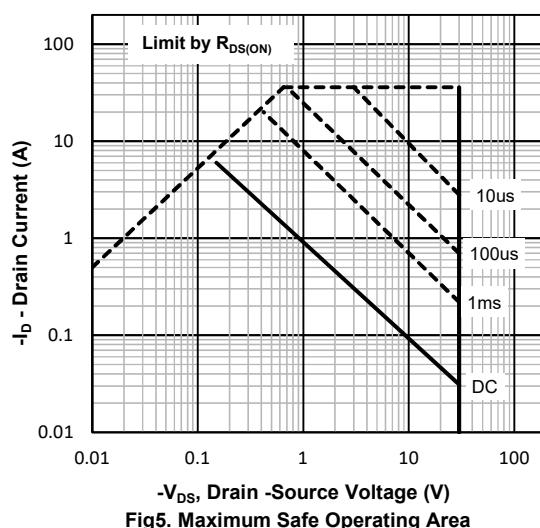


Fig5. Maximum Safe Operating Area

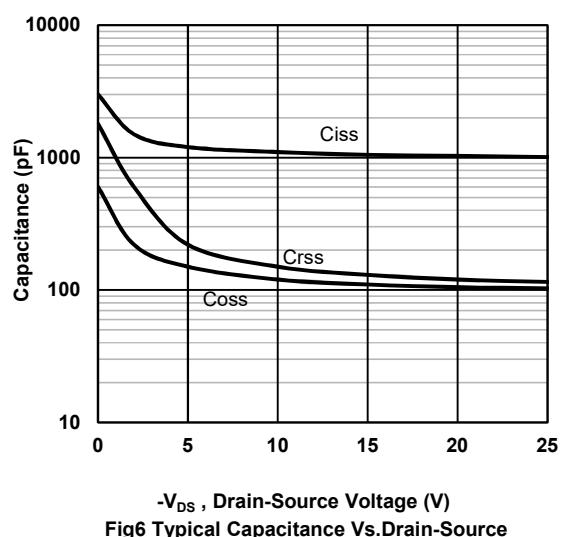
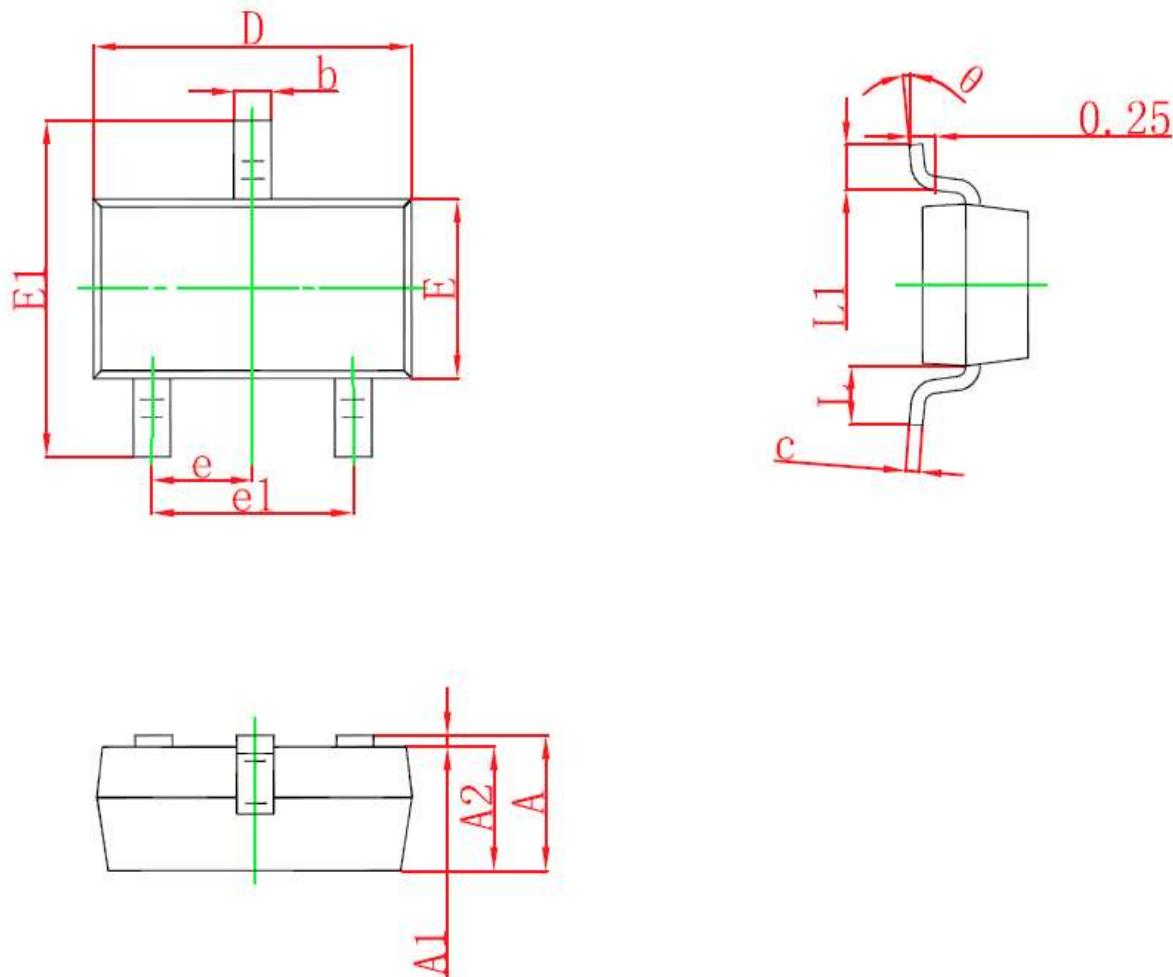


Fig6 Typical Capacitance Vs.Drain-Source

## SOT-23 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°